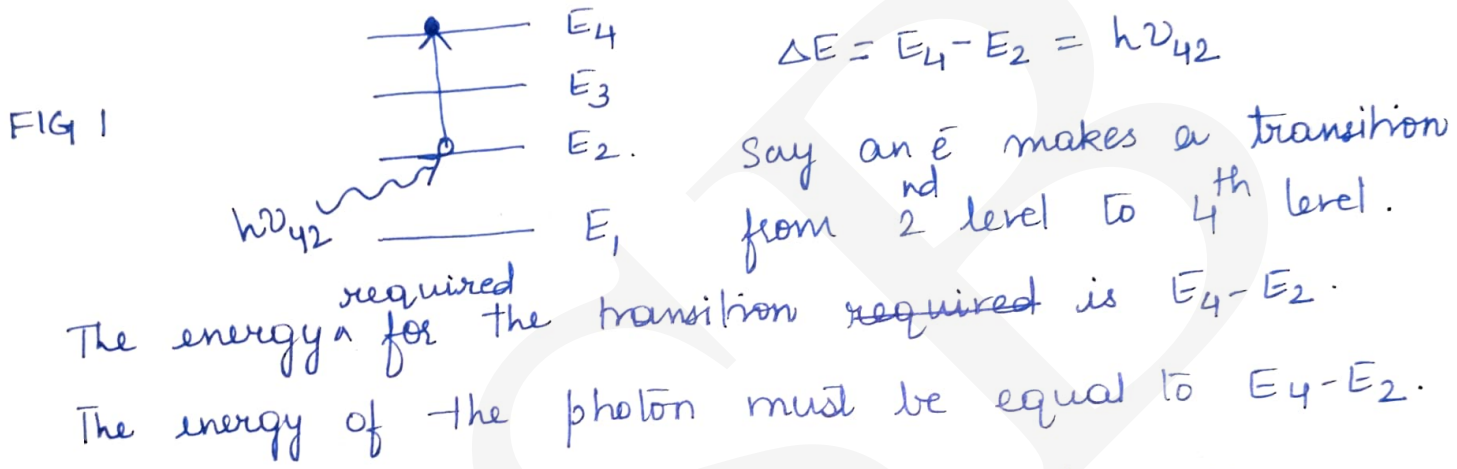


ABSORPTION AND EMISSION OF LIGHT IN

METALS, INSULATORS AND SEMICONDUCTORS

The absorption and emission of electromagnetic radiation may involve e^- transition from one energy state to another.



* An e^- by absorbing photon of required energy makes a transition to excited state.

* Electron can't remain in excited state indefinitely. After a short time it falls/decays back to its ground state with a reemission of em radiation.

ABSORPTION & EMISSION IN METALS

Absorption

Consider the e^- energy band scheme as shown in fig 2a.

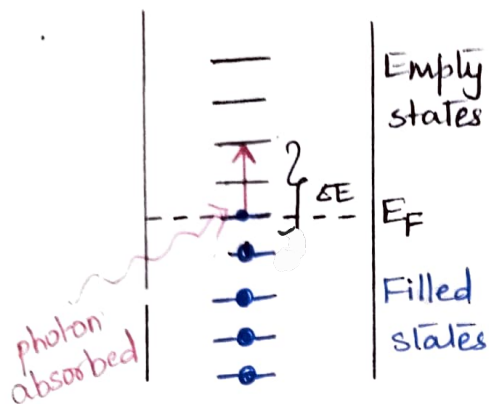


fig 2a

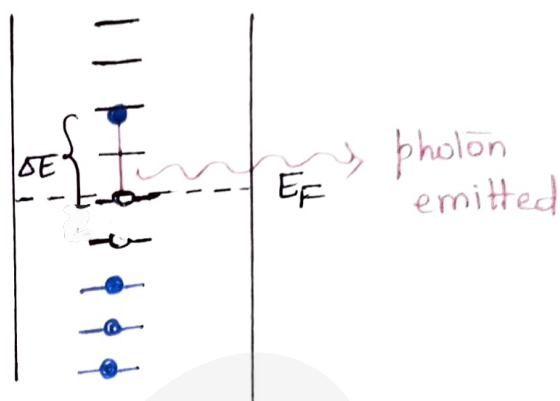


fig 2b

In metals valence band & conduction band overlap and there exists plenty of empty states in conduction band.

* All frequencies of visible light are absorbed by metals because many empty energy levels are available to engage transition as shown in fig 2a.

* The absorption occurs upto a thickness of $0.1 \mu\text{m}$ of metal.

* Apart from visible, metals are opaque to radio, IR, visible and middle of UV radiation.

* Metals are transparent to x-rays & γ rays

NOTE Extra $\therefore E_r \sim 1 - \frac{Ne^2}{\epsilon_0 m_e \omega^2}$

as ω becomes larger n larger $E_r \sim 1$
 $\therefore$ refractive index $n = \sqrt{E_r \mu_r}$, for slight-
 magnetic material $\mu_r = 1 \therefore n = \sqrt{E_r} = 1$
 $\therefore$ transparent]

Emission

Consider fig 2b, absorbed photon is reemitted with the same energy.

- * If a visible photon is absorbed, the absorbed photon is re-emitted from the surface in the form of visible light of the same wavelength, which appears as reflected light.
- * Reflectivity of most metals is between 0.90 & 0.95.
- * Color of the metal is characteristic of wavelength distribution of radiation that is reflected.
- * Metals which reemit in the entire visible range appear silvery. Eg Ag & Al.

Absorption and emission in insulators

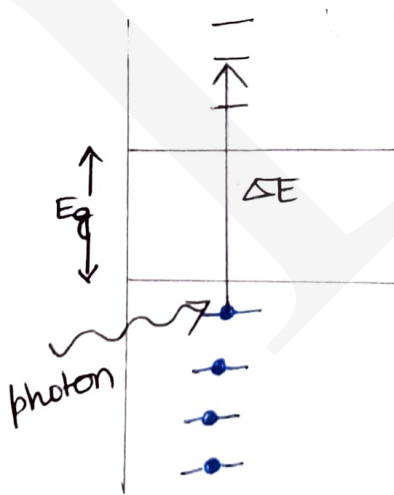


fig 3a

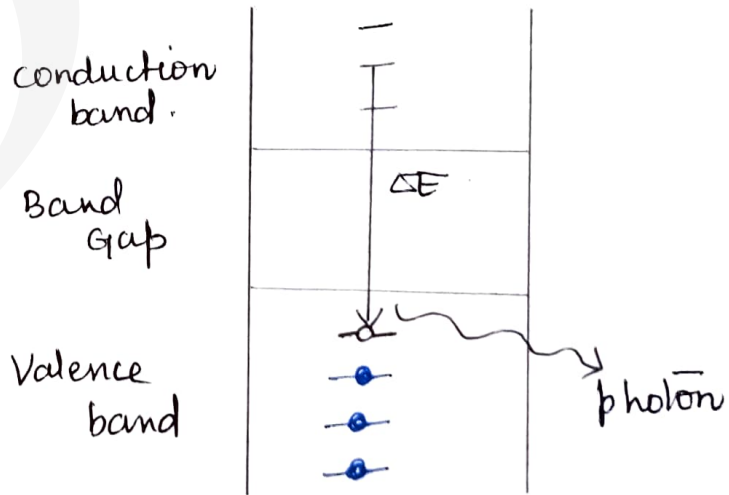


fig 3b

Absorption

Absorption of light photon may occur in an insulator. It results in excitation of an e^- from VB to CB after crossing band gap E_g as shown in fig 3a.

* This results in formation of e^- & hole in CB & VB respectively.

* As E_g is the difference band gap, any excitation is possible if photon of energy.

$h\nu > E_g$ impinges the e^- in valence band

* Most of the elements have band gap greater than 3 eV. Hence, using above equation one can find minimum energy required for transition to happen.

$$\text{As } h\nu = \frac{hc}{\lambda} \quad \text{substituting } h = 6.62 \times 10^{-34} \text{ J s}$$

$$c = 3 \times 10^8 \text{ m/s}$$

and $\lambda = 400 \text{ nm} = 400 \times 10^{-9} \text{ m}$ which is minimum wavelength (or maximum freq) of visible light we get.

$$E_g = 3.1 \text{ eV}$$

From this we conclude that most of the visible light's energy won't be sufficient—

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to excite an e^- across the band gap of an insulator.

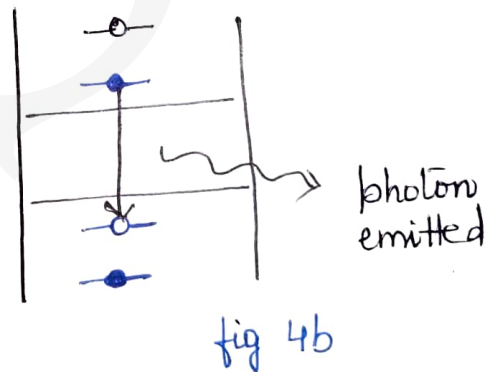
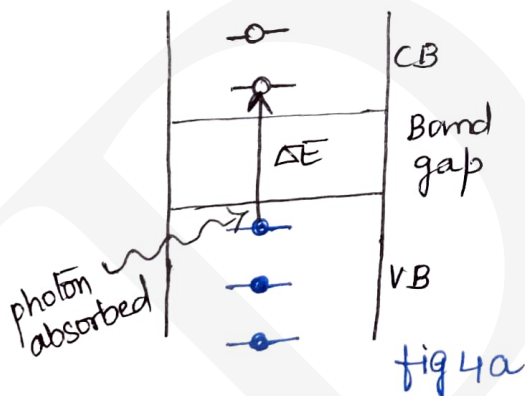
* As no absorption takes place, these materials appear transparent in purest state.

Emission

* An emission would be somewhat like fig 3b, in case any absorption occurs.

* The e^- while recombining with a hole in VB would emit a photon of same energy that it absorbed to make upward transition from VB to CB.

Absorption and emission in semiconductor



* Light photon is absorbed by an e^- to make an upward transition from VB to CB. The energy of the photon $h\nu$ should be greater than band gap.

$$h\nu > E_g$$

* Most of the semiconductor materials have band gap between 0.6 to 1.8 eV.

* Energy gap corresponding to maximum wavelength i.e. 700 nm (minimum energy) photon would give us minimum Energy —

$$E_{g \min} = \frac{hc}{\lambda} = \left(\frac{6.6 \times 10^{-34} \times 3 \times 10^8}{700 \times 10^{-9}} \right) / (1.6 \times 10^{-19})$$

$$E_{g \min} = 1.8 \text{ eV}$$

* Thus, all the visible light is absorbed by the semiconductor and it appears opaque.

* When an e^- in CB recombine with a hole in VB, photon is emitted as shown in figure 4.6.

Extra

Absorption & Emission in dielectrics.

* Dielectric solids have a wide band gap. Energy levels other than VB & CB can participate in transition.

* Impurity or other electrically active defect can introduce new energy levels within band gap.

* Light radiation of specific wavelengths may be

emitted as a result of e^- transitions involving these levels within the band gap as shown in fig 5b.

* Photon emission could be multistep (5a) or phonon & photon emission can complete the transition as shown in fig 5b.

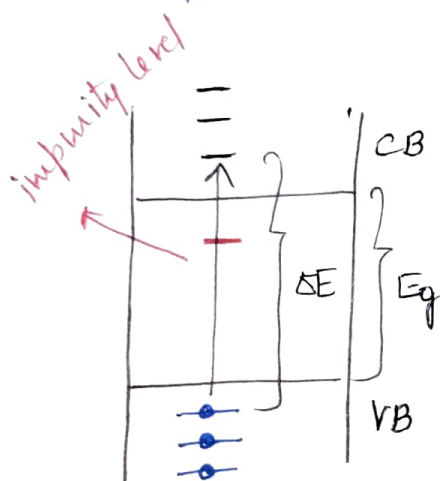


fig 5a

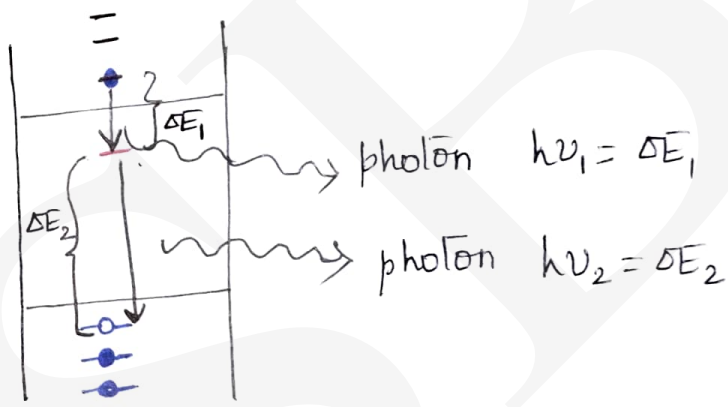


fig 5b.

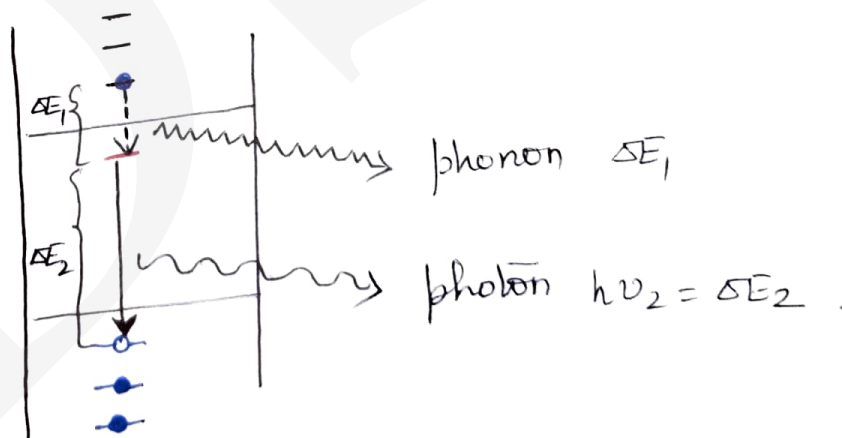


fig 5c.